Round Types

FEATURES

- \bullet Standard T1 3 ϕ • 1/4 Duty Cycle
- Pulse Rate: 2.4Hz (VDD=5V) • Operating Voltage: 3V~10V (DC)
- Easily be driven by TTL &C-MOS circuit no external circuit needed

ABSOLUTE MAXIMUN RATINGS

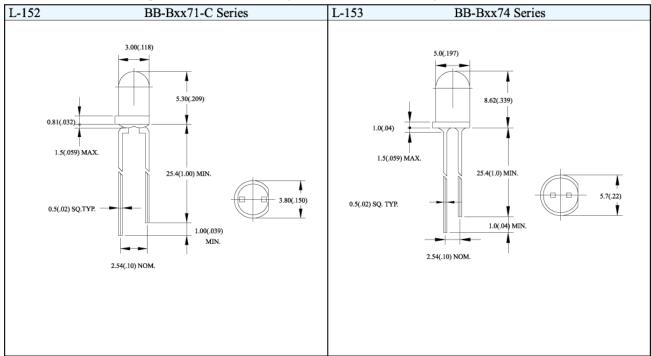
Operating Temperature Range	℃~80℃
Storage Temperature Range	℃~85℃
Operating Voltage(Max)	10 Volt
Reverse Voltage(Max)	5 Volt

Package	Part No.	Chip				Pulse Rate(Hz) VDD=5V (Hz)			Luminous Intensity IF=25mA (mcd)		Viewing	
		Material	Emitted Color	Peak Wave Length λp(nm)	Lens Appearance	Min.	Тур.	Max.	Min.	Тур.	Angle 2 θ 1/2 (deg)	Drawing No.
T-1 Standard 1.0" Lead 3 φ	BB-B5171-C	GaP/GaP	Bright Red	700	Red Diffused	2.0			2.0	6.0	45	L-152
	BB-B4571-C	GaAsP/GaP	Hi-Eff Red	635					8.0	25.0		
	BB-B6171-C	GaAlAs	Super Red	660					15.0	40.0		
	BB-B2171-C	GaP/GaP	Green	568	Green Diffused				8.0	25.0		
	BB-BX1171-C	GaP/GaP	Hi-Eff Y.G	568					10.0	30.0		
	BB-B3171-C	GaAsP/GaP	Yellow	585	Yellow Diffused				6.0	20.0		
	BB-B4171-C	GaAsP/GaP	Orange	635	Orange Diffused		2.4	2.8	8.0	25.0		
T-13/4 Standard 1.0" Lead 5 ϕ	BB-B5174	GaP/GaP	Bright Red	700	Red Diffused	2.0	2.4	2.6	4.0	12.0	45	
	BB-B4574	GaAsP/GaP	Hi-Eff Red	635					12.0	40.0		L-153
	BB-B6174	GaAlAs	Super Red	660					20.0	60.0		
	BB-B2174	GaP/GaP	Green	568	Green Diffused				12.0	40.0		
	BB-BX1174	GaP/GaP	Hi-Eff Y.G	568					5.0	50.0		
	BB-B3174	GaAsP/GaP	Yellow	585	Yellow Diffused				10.0	35.0		
	BB-B4174	GaAsP/GaP	Orange	635	Orange Diffused				12.0	40.0		

Remark : 1.Hi-Eff Red / High-Efficiency Red \circ

2.Trans / Transparent o

3.2 θ 1/2 The off-axis angle at which the luminous intensity is half the axial luminous intensity \circ



Notes: 1.All Dimensions are millimeters (inches).

2. Tolerance is ± 0.25 mm (.010").

AMERICAN BRIGHT